NSN 5961-01-107-2018

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Inclosure Material:

Metal

Overall Length:

0.326 inches

Overall Diameter:

0.830 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Internal Junction Configuration:

Npn

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 collector to emitter voltage/static/base open and 450.0 collector to emitter voltage, dc with specified circuit between base and emitter

and 7.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

30.00 amperes source cutoff current and 5.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

1 case and 2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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